

Vishay Siliconix

## Single-Ended Bus Transceiver

### **DESCRIPTION**

The Si9243AEY is a monolithic bus transceiver designed to provide bidirectional serial communication in automotive diagnostic applications.

The device incorporates protection against overvoltages and short circuits to  $V_{\mbox{\footnotesize{BAT}}}.$  The transceiver pin is protected and can be driven beyond the V<sub>BAT</sub> voltage.

The RX output is capable of driving CMOS or 1 x LSTTL load.

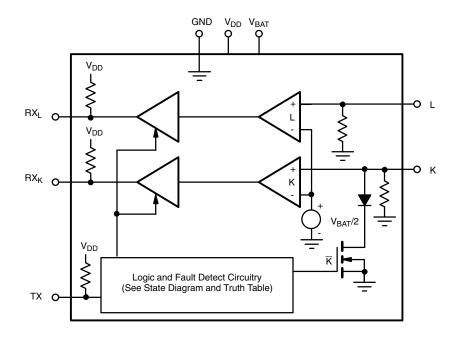
The Si9243AEY is built on the Vishay Siliconix BiC/DMOS process. This process supports bipolar transistors, CMOS, and DMOS. An epitaxial layer prevents latchup.

The Si9243AEY is available in a 8-pin SO package and operates over the automotive temperature range (- 40 °C to 125 °C). The Si9243AEY is available in both standard and lead (Pb)-free packages.

### **FEATURES**

- · Operating Power Supply Range  $6 \text{ V} \leq \text{ V}_{BAT} \leq 36 \text{ V}$
- Reverse Battery Protection Down to  $V_{BAT} \ge$  24 V
- Standby Mode With Very Low Current Consumption  $I_{BAT(SB)} = 1 \mu A$  at  $V_{DD} = 0.5 V$
- Low Quiescent Current in OFF Condition  $I_{BAT}$  = 120  $\mu A$  and  $I_{DD} \le$  10 A
- ISO 9141 Compatible
- Overtemperature Shutdown Function For K Output
- Defined K Output OFF for Open GND
- Defined Receive Output Status for Open K Input
- Defined K Output OFF for TX Input Open
- Open Drain Fault Output
- 2 kV ESD
- Typical Transmit Speeds of 200 kBaud

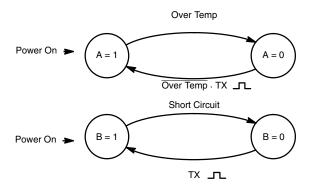
### PIN CONFIGURATION AND FUNCTIONAL BLOCK DIAGRAM



# Vishay Siliconix



### **OUTPUT TABLE AND STATE DIAGRAMS**



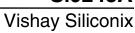
Note: Over Temp is an internal condition, not meant to be a logic signal.

| INP                        | UTS | STATE<br>VARIABLE |   | OUTPUT<br>TABLE |     |        |               |
|----------------------------|-----|-------------------|---|-----------------|-----|--------|---------------|
| TX                         | L   | Α                 | В | K               | RXK | $RX_L$ | Comments      |
| 0                          | 0   | 1                 | 1 | 0               | 0   | 0      |               |
| 1                          | 1   | 1                 | 1 | 1               | 1   | 1      |               |
| 0                          | 1   | 1                 | 1 | 0               | 0   | 1      |               |
| 1                          | 0   | 1                 | 1 | 1               | 1   | 0      |               |
| Χ                          | L   | 0                 | 1 | HiZ             | K   | L      | Over Temp     |
| 0                          | L   | 1                 | 0 | HiZ             | K   | L      | Short Circuit |
|                            |     |                   |   |                 |     |        |               |
| 1                          | 1   | 1                 | 1 | 1               | 1   | 1      | Receive Mode  |
| 1                          | 0   | 1                 | 1 | 0               | 0   | 0      |               |
| X = "1" or "0"             |     |                   |   |                 |     |        |               |
| Hi7 = High Impedance State |     |                   |   |                 |     |        |               |

| ABSOLUTE MAXIMUM RATINGS  |  |      |  |  |
|---|--|------|--|--|
| Parameter   | Limit                                      | Unit |  |  |
| Voltages Referenced to Ground                                       | •  |      |  |  |
| Voltage On V <sub>BAT</sub>   | - 24 to 45                                 |      |  |  |
| Voltage K, L  | - 16 to (V <sub>BAT</sub> + 1)             | V    |  |  |
| Voltage Difference V <sub>(VBAT, K, L)</sub>                        | 55   | 1    |  |  |
| Voltage On Any Pin (Except V <sub>BAT</sub> , K, L) or Max. Current | - 0.3 V to (V <sub>DD</sub> + 0.3 V) or 10 | mA   |  |  |
| Voltage on V <sub>DD</sub>  | 7  | V    |  |  |
| K Pin Only, Short Circuit Duration (to V <sub>BAT</sub> or GND)     | Continuous                                 |      |  |  |
| Operating Temperature (T <sub>A</sub> )                             | - 40 to 125                                | °C   |  |  |
| Junction and Storage Temperature                                    | - 55 to 150                                | 1    |  |  |
| Thermal Impedance $(\Theta_{JA})$                                   | 125  | °C/W |  |  |

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

| RECOMMENDED OPERATING RANGE   |                      |      |  |
|-------------------------------|----------------------|------|--|
| Parameter                     | Limit                | Unit |  |
| Voltages Referenced to Ground |                      |      |  |
| $V_{DD}$                      | 4.5 to 5.5           |      |  |
| V <sub>BAT</sub>              | 6 to 36              | V    |  |
| K, L                          | 6 to 36              |      |  |
| Digital Inputs                | 0 to V <sub>DD</sub> |      |  |





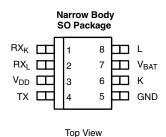
| Parameter  | Symbol                | Test Conditions Unless Specified $V_{DD} = 4.5 \text{ V to } 5.5 \text{ V}$ $V_{BAT} = 6 \text{ V to } 36 \text{ V}$           |   | Temp. <sup>a</sup> | <b>Limits</b><br>- 40 to 125 °C |                       | Unit                 |           |
|--|-----------------------|--|---|--------------------|---------------------------------|-----------------------|----------------------|-----------|
| raiailietei  | Symbol                |  |   |                    | Min.b                           | Typ. <sup>c</sup>     | Max.b                | Onit      |
| Transmitter and Logic Levels                                       |                       |  |   |                    |                                 | l                     |                      |           |
| TX Input Low Voltage   | $V_{ILT}$             |  |   | Full               |                                 |                       | 1.5                  | V         |
| TX Input High Voltage  | V <sub>IHT</sub>      |  |   | Full               | 3.5                             |                       |                      | \ \       |
| TX Input Capacitance <sup>d</sup>                                  | C <sub>INT</sub>      |  |   | Full               |                                 |                       | 10                   | pF        |
| TX Input Pull-up Resistance  | R <sub>TX</sub>       | V <sub>DD</sub> = 5.5  | V, TX = 1.5 V, 3.5 V  | Full               | 10                              | 20                    | 40                   | kΩ        |
| K Transmit   |                       | l e  |   |                    | L                               |                       |                      |           |
|  |                       | $R_L = 510 \ \Omega \pm 5 \ \%, \ V_{BAT} = 6 \ to \ 18$   |   | Full               |                                 |                       | 0.2 V <sub>BAT</sub> |           |
| K Output Low Voltage   | V <sub>OLK</sub>      | $R_L = 1 \text{ k}\Omega \pm 5 \%, V_{BAT} = 16 \text{ to } 36$  |   | Full               |                                 |                       | 0.2 V <sub>BAT</sub> | 1         |
|  |                       | R <sub>L</sub> = 510   | $\Omega \pm 5$ %, $V_{BAT} = 4.5$   | Full               |                                 |                       | 1.2                  | V         |
| V.O  | M                     | $R_L = 510 \Omega \pm 5 \%$ , $V_{BAT} = 4.5 \text{ to } 18$   |   | Full               | 0.95 V <sub>BAT</sub>           |                       |                      | 1         |
| K Output High Voltage  | V <sub>OHK</sub>      | $R_L = 1 \text{ k}\Omega$  | ± 5 %, V <sub>BAT</sub> = 16 to 36  | Full               | 0.95 V <sub>BAT</sub>           |                       |                      | 1         |
| K Rise, Fall Times   | t <sub>r</sub> , tf   | Se   | ee Test Circuit   | Full               |                                 |                       | 9.6                  | μs        |
| K Output Sink Resistance   | Rsi                   |  |   | Full               |                                 |                       | 110                  | Ω         |
| K Output Capacitance <sup>d</sup>                                  | Co                    |  | TX = 0 V  | Full               |                                 |                       | 20                   | pF        |
| Receiver   | -                     |  |   |                    |                                 |                       |                      | <u> </u>  |
| L and K Input High Voltage   | V <sub>IH</sub>       |  |   | Full               | 0.65 V <sub>BAT</sub>           |                       |                      |           |
| L and K Input Hysteresis <sup>c, d</sup>                           | V <sub>HYS</sub>      |  |   | Full               |                                 | 0.05 V <sub>BAT</sub> |                      | V         |
| L and K Input Currents   | I <sub>IH</sub>       |  | V <sub>IH</sub> = V <sub>BAT</sub>  | Full               |                                 |                       | 20                   | μΑ        |
| RX <sub>L</sub> and RX <sub>K</sub> Output Low Voltage             | V <sub>OLR</sub>      | TX = 4   | $V_{ILK}$ , $V_{ILL} = 0.35 V_{BAT}$<br>$I_{OLR} = 1 \text{ mA}$                      | Full               |                                 |                       | 0.4                  | V         |
| RX <sub>L</sub> and RX <sub>K</sub> Pull-up Resistance             | R <sub>RX</sub>       |  | <u> </u>  | Full               | 5                               |                       | 20                   | kΩ        |
|  |                       | $R_L = 510 \ \Omega \pm 5 \ \%$ , $V_{BAT} = 6 \ V$ to 18 V $C_L = 10 \ nF$ , See Test Circuit                                 |   | Full               |                                 | 3                     | 10                   | -<br>- μs |
| RX <sub>K</sub> Turn On Delay                                      | t <sub>d(on)</sub>    | $R_L$ = 1 k $\Omega$ ± 5 %, $V_{BAT}$ = 16 V to 36 V $C_L$ = 4.7 nF, See Test Circuit  |   | Full               |                                 | 3                     | 10                   |           |
| DV Turn Off Dolow  |                       | $R_L$ = 510 $\Omega$ ± 5 %, $V_{BAT}$ = 6 V to 18 V $C_L$ = 10 nF, See Test Circuit  |   | Full               |                                 | 3                     | 10                   |           |
| RX <sub>K</sub> Turn Off Delay                                     | t <sub>d(off)</sub>   | $R_L = 1 \text{ k}\Omega \pm 5$ $C_L = 4.7$  | $R_L$ = 1 k $\Omega$ ± 5 %, $V_{BAT}$ = 16 V to 36 V $C_L$ = 4.7 nF, See Test Circuit |                    |                                 | 3                     | 10                   |           |
| Supplies   |                       |  |   |                    |                                 |                       |                      |           |
| Bat Supply Current On  | I <sub>BAT(on)</sub>  |  | 0 V, V <sub>BAT</sub> ≤ 16 V  | Full               |                                 | 1.2                   | 3                    | mA        |
| Bat Supply Current Off   | I <sub>BAT(off)</sub> | $V_{IHT} \leq V_{TX}$  | $V_{IHK} \le V_{K}, V_{IHL} \le V_{L}$<br>$V_{BAT} \le 12 V$                          | Full               |                                 | 120                   | 220                  | μΑ        |
| Bat Supply Current Standby   | I <sub>BAT(SB)</sub>  |  | 0.5 V, V <sub>BAT</sub> ≤ 12 V  | Full               |                                 | < 1                   | 10                   |           |
| Logic Supply Current On  | I <sub>DD(on)</sub>   |  | ≤ 5.5 V, TX = 0 V   | Full               |                                 | 1.4                   | 2.3                  | mA        |
| Logic Supply Current Off   | I <sub>DD(off)</sub>  | $V_{IHT} \le V_{TX}, V_{IHK} \le V_K, V_{IHL} \le V_L$ $V_{BAT} \le 12 \text{ V}$  |   | Full               |                                 |                       | 10                   | μА        |
| Miscellaneous  |                       |  |   |                    |                                 |                       |                      |           |
| TX Transmit Baud Rate  | BR <sub>T</sub>       |  | $R_L = 510 \Omega, C_L = 10 \text{ nF}$<br>6 V < $V_{BAT}$ < 16 V, $C_{RX}$ = 20 pF   |                    | 10.4                            |                       |                      | kBaud     |
| RX <sub>L</sub> and RX <sub>K</sub> Receive Baud Rate <sup>c</sup> | BR <sub>R</sub>       |  |   |                    |                                 | 200                   |                      | NDauC     |
| Transmission Frequency   | f <sub>K-RXK</sub>    | $6 \text{ V} < \text{V}_{\text{BAT}} < 16 \text{ V}, \text{R}_{\text{K}} = 510 \Omega, \text{C}_{\text{K}} \le 1.3 \text{ nF}$ |   | Full               | 50                              | 200                   |                      | kHz       |
| TX Minimum Pulse Width <sup>d, e</sup>                             | t <sub>TX</sub>       | Dru - K - Z K  |   | Full               | 1                               |                       |                      | μs        |
| Over Temperature Shutdown <sup>d</sup>                             | T <sub>SHUT</sub>     | Temperature Rising   |   |                    | 160                             | 180                   |                      |           |
| Temperature Shutdown Hysteresis <sup>c</sup>                       | T <sub>HYST</sub>     | <u> </u>   |   |                    |                                 | 30                    |                      | °C        |

- a. Room = 25  $^{\circ}$ C, Cold and Hot = as determined by the operating temperature suffix.
- b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet. c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- d. Guaranteed by design, not subject to production test. e. Minimum pulse width to reset a fault condition.

## Vishay Siliconix

PIN CONFIGURATION





| ORDERING INFORMATION             |                   |  |  |
|----------------------------------|-------------------|--|--|
| Part Number                      | Temperature Range |  |  |
| Si9243AEY-T1                     | - 40 to 125 °C    |  |  |
| Si9243AEY-T1-E3 (Lead (Pb)-free) |                   |  |  |

| PIN DESCRIPTION |                 |                                   |  |  |
|-----------------|-----------------|-----------------------------------|--|--|
| Pin Number      | Symbol          | Description                       |  |  |
| 1               | RX <sub>K</sub> | K Receiver, Output                |  |  |
| 2               | $RX_L$          | L Receiver, Output                |  |  |
| 3               | $V_{DD}$        | Positive Power Supply             |  |  |
| 4               | TX              | Transmit, Input                   |  |  |
| 5               | GND             | Ground Connection                 |  |  |
| 6               | K               | K Transmit/Receive, Bidirectional |  |  |
| 7               | $V_{BAT}$       | Battery Power Supply              |  |  |
| 8               | L               | L Transmit, Input                 |  |  |

## **FUNCTIONAL DESCRIPTION**

The Si9243AEY can be either in transmit or receive mode and it contains over temperature, and short circuit  $V_{\text{BAT}}$  fault detection circuits.

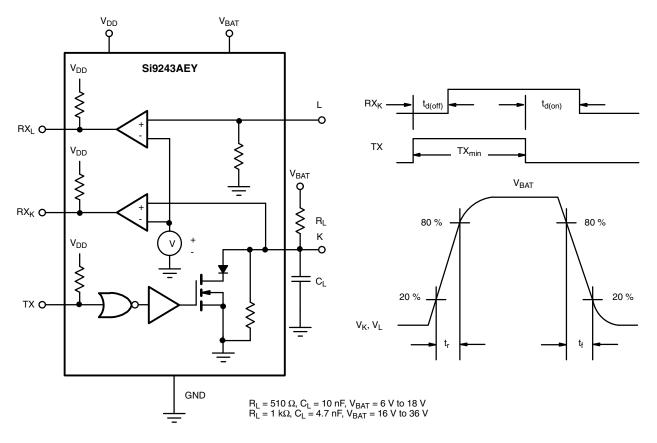
The voltage on the K and L pins are internally compared to  $V_{BAT/2}$ . If the voltage on the K or L pin is less than  $V_{BAT/2}$  then  $RX_K$  or  $RX_L$  output will be "low". If the voltage on the K or L pin is greater than  $V_{BAT/2}$  then  $RX_K$  or  $RX_L$  output will be "high".

In order to be in transmit mode, TX must be set "low". The TX signal is then internally inverted and turns the MOSFET on, causing the K pin to be "low". In transmit mode, the processor monitors the  $\mathsf{RX}_\mathsf{K}$  and  $\mathsf{TX}.$  When the two mirror each other there is no fault. In the event of over temperature, or short circuit to VBAT, the Si9243AEY will turn off the K output to protect the IC. The K pin will stay in high impedance and RXK will follow the K pin. The fault will be reset when TX is toggled high.  $RX_K$ ,  $RX_L$  and TX pins have internal pull up resistor to V<sub>DD</sub> while K and L pins have internal pull down resistors. When any one of the TX, V<sub>BAT</sub> or GND pins is open the K output is off.

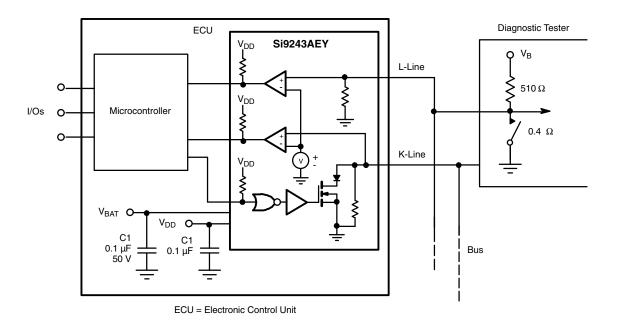
When the TX pin is set "high" the Si9243AEY is in receive mode and the internal MOSFET is turned off. RXI and RXK outputs will follow L and K inputs respectively.



## **TEST CIRCUIT AND TIMING DIAGRAMS (TRANSMIT ONLY)**



### **APPLICATIONS CIRCUIT**

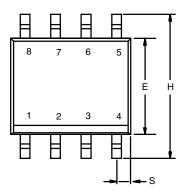


Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?70788.

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SOIC (NARROW): 8-LEAD JEDEC Part Number: MS-012







|                              | MILLIMETERS |      | INCHES      |       |  |  |
|------------------------------|-------------|------|-------------|-------|--|--|
| DIM                          | Min         | Max  | Min         | Max   |  |  |
| Α                            | 1.35        | 1.75 | 0.053       | 0.069 |  |  |
| A <sub>1</sub>               | 0.10        | 0.20 | 0.004       | 0.008 |  |  |
| В                            | 0.35        | 0.51 | 0.014       | 0.020 |  |  |
| С                            | 0.19        | 0.25 | 0.0075      | 0.010 |  |  |
| D                            | 4.80        | 5.00 | 0.189       | 0.196 |  |  |
| Е                            | 3.80        | 4.00 | 0.150       | 0.157 |  |  |
| е                            | 1.27        | BSC  | 0.050 BSC   |       |  |  |
| Н                            | 5.80        | 6.20 | 0.228       | 0.244 |  |  |
| h                            | 0.25        | 0.50 | 0.010       | 0.020 |  |  |
| L                            | 0.50        | 0.93 | 0.020       | 0.037 |  |  |
| q                            | 0°          | 8°   | 0°          | 8°    |  |  |
| S                            | 0.44        | 0.64 | 0.018 0.026 |       |  |  |
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